SHANGHAI SUNRISE ELECTRONICS CO., LTD.

DF005 THRU DF10 SINGLE PHASE GLASS PASSIVATED BRIDGE RECTIFIER VOLTAGE: 50 TO 1000V CURRENT: 1.0A

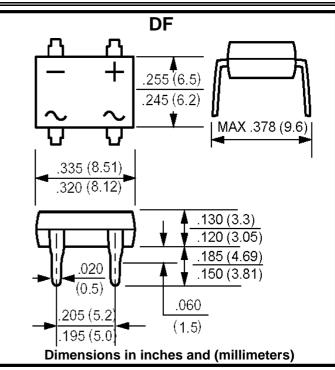
TECHNICAL SPECIFICATION

FEATURES

- Ideal for printed circuit board
- Reliable low cost construction utilizing molded plastic technique
- Surge overload rating: 50 A peak
- High temperature soldering guaranteed: 250°C/10sec/ at terminals

MECHANICAL DATA

- Terminal: Plated leads solderable per MIL-STD 202E, method 208C
- Case: UL-94 Class V-O recognized flame retardant epoxy
- Polarity: Polarity symbol marked on body
- Mounting position: Any



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Single-phase, half-wave, 60Hz, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

RATINGS	SYMBOL	DF	DF	DF	DF	DF	DF	DF	UNITS
		005	01	02	04	06	08	10	
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current		1.0							А
$(T_a=40^{\circ}C)$	I _{F(AV)}	1.0							
Peak Forward Surge Current (8.3ms single	1	50							А
half sine-wave superimposed on rated load)	I _{FSM} 50								~
Maximum Instantaneous Forward Voltage	V _F	1.1							V
(at forward current 1.0A)	۷F								v
Maximum DC Reverse Current T _a =25°C	10.0								μΑ
(at rated DC blocking voltage) $T_a=125^{\circ}C$	I _R		500						μA
Typical Junction capacitance (Note 1)	CJ	25							pF
Typical Thermal Resistance (Note 2)	R _θ (Ja)	40							°C/W
Storage and Operating Junction Temperature	T _{STG} ,T _J	-55 to +150					°C		
Note: 1. Measured at 1.0 MHz and applied voltage	no of 4 0 V								

1. Measured at 1.0 MHz and applied voltage of 4.0 $V_{\rm dc}$

2. Thermal Resistance from junction to Ambient mounted on P.C. Board with 13×13mm copper pads.

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